

Rev. 1.4

#### **Dual 0.1W Headphone Amplifier with Active-high shutdown mode**

#### **FEATURES**

- 2.5V~5.5V Power supply.
- Thermal shutdown Protection.
- Low current shutdown mode
- "Click and Pop" suppression
- No bootstrap capacitors required
- Low noise during turn-on and turn-off transitions
- Active-high shutdown mode
- Lead free and green package available. (RoHS Compliant)
- Space Saving Package
  - -- 8-pin MSOP package.

#### **APPLICATION**

- Portable electronic devices
- Mobile Phones
- Microphone Preamplifier
- PDA's

#### **GENERAL DESCRIPTION**

The LY8601 is a dual 0.1W audio power amplifier. It is capable of driving 16  $\Omega$  load at a continuous average output of 0.1W/0.1% distortion (THD+N) from a 5.0V power supply.

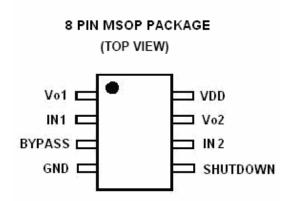
The LY8601 primarily designed for high quality application in other portable communication device. And the LY8601 audio amplifier features low power consumption shutdown mode. It is achieved by driving the shutdown pin with logic high and it has an internal thermal shutdown protection feature.

The unity-gain stable LY8601 can be configured by external gain-setting resistors.

The LY8601 audio amplifier was designed specifically to provide high quality output power with a minimal amount of external components. The LY8601 does not require bootstrap capacitors, and the LY8601 is ideally suited for other low voltage applications or portable electronic devices where minimal power consumption is a primary requirement.

# **PIN CONFIGURATION**

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# **PIN DESCRIPTION**

SYMBOL	Pin No.	DESCRIPTION
OTWIDOL	MSOP	DEGGKII HON
Vo1	1	Audio output of Left channel.
IN1	2	Audio Input of Left channel.
BYPASS	3	Bypass pin
GND	4	Ground
SHUTDOWN	5	Shutdown Pin.(when active High is shutdown mode)
IN2	6	Audio Input of Right channel.
Vo2	7	Audio output of Right channel.
$V_{DD}$	8	Power Supply

# **APPLICATION CIRCUIT**

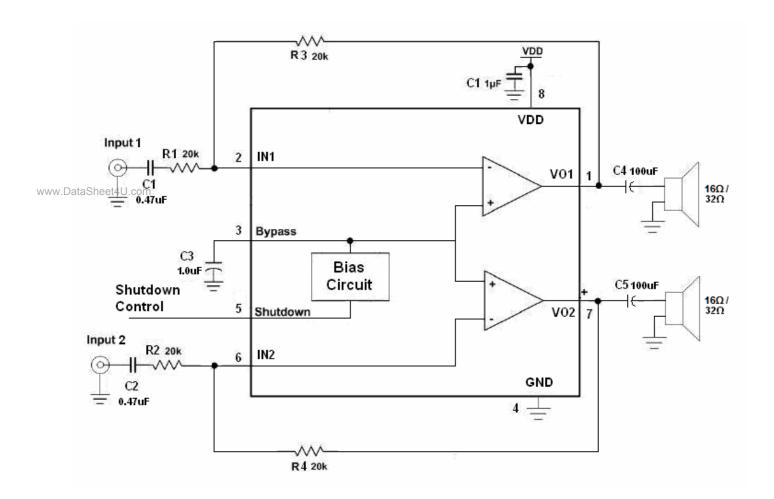


Figure 1. Typical Audio Amplifier Application Circuit



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# **ABSOLUTE MAXIMUN RATINGS\***

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	Vdd	6.0	V
Operating Temperature	TA	-40 to 85 (I grade)	$^{\circ}$
Input Voltage	Vı	-0.3V to VDD +0.3V	V
Storage Temperature	Тѕтс	-65 to 150	$^{\circ}$
Power Dissipation	PD	Internally Limited	W
ESD Susceptibility	Vesd	2000	V
Junction Temperature	Тумах	150	$^{\circ}$
Soldering Temperature (under 10 sec)	Tsolder	260	$^{\circ}$

# DC ELECTRICAL CHARACTERISTICS (VDD=5V, TA=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Power Supply Current	ו חחו	$V_{IN} = 0V$ , $I_O = 0A$ , No Load	-	3.5	9.0	mΑ
r ower Supply Current		$V_{IN} = 0V$ , $I_O = 0A$ , $8\Omega$ Load	-	4.0	10.0	mΑ
Shutdown Current	Isd	Vshutdown = Vdd	-	0.1	2.0	μA
Shutdown Voltage Input High	Vsdih		0.8xV <sub>DD</sub>	-	-	V
Shutdown Voltage Input Low	Vsdil		-	-	$0.2xV_{DD}$	V
Output Offset Voltage	Vos		-	7.0	50.0	mV
	Ро	THD+N=0.1%,f =1kHz,RL=8 $\Omega$		258		mW
Output Power		THD+N=0.1%,f =1kHz,RL=16 $\Omega$		114		
ataSheet4U.com		THD+N=0.1%,f =1kHz,RL=32 $\Omega$		93		
Total Harmonic Distortion+ Noise	THD+N	Po = 50mW; RL = $32\Omega$ f = 20Hz to 20kHz	-	0.4		%
Power Supply Rejection Ratio	PSRR	C <sub>B</sub> =1.0uF,Vripple = 200mVPP f = 1kHz, Input terminated with $50 \Omega$ .	-	66	-	dB
Thermal Shutdown Temperature	TsD		150	170	190	$^{\circ}\!\mathbb{C}$

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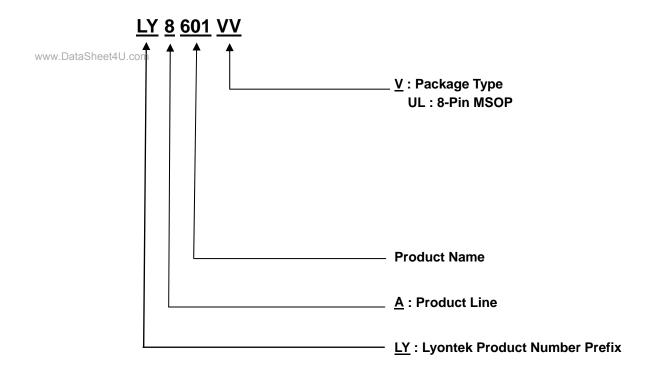
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# Dual 0.1W Headphone Amplifier with Active-high shutdown mode

# DC ELECTRICAL CHARACTERISTICS (VDD=3V, TA=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Power Supply Current	IDD	$V_{IN} = 0V$ , $I_O = 0A$ , No Load	-	3.0	8.0	mΑ
r ower Supply Current		$V_{IN} = 0V$ , $I_O = 0A$ , $8\Omega$ Load	-	3.5	9.0	mΑ
Shutdown Current	Isp	Vshutdown = Vdd	-	0.1	2.0	μΑ
Shutdown Voltage Input High	Vsdih		0.8xV <sub>D</sub>	-	-	V
Shutdown Voltage Input Low	Vsdil		-	-	$0.2xV_{DD}$	V
Output Offset Voltage	Vos		-	7.0	50.0	mV
		THD+N=0.1%,f =1kHz,RL=8 $\Omega$		105		
Output Power	Po	THD+N=0.1%,f =1kHz,RL=16 $\Omega$		73		mW
		THD+N=0.1%,f =1kHz,RL=32Ω		35		
Total Harmonic Distortion+ Noise	THD+N	Po = 25mW; RL = $32\Omega$ f = 20Hz to 20kHz	-	0.4		%
Power Supply Rejection Ratio	PSRR	C <sub>B</sub> =1.0uF,Vripple = 200mVPP f = 1kHz, Input terminated with $50\Omega$ .		62	-	dB
Thermal Shutdown Temperature	Tsp		150	170	190	$^{\circ}\!\mathbb{C}$

#### ORDERING INFORMATION

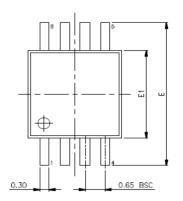


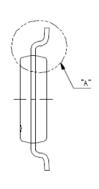
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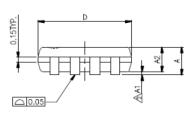
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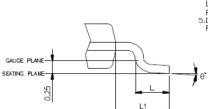
#### PACKAGE OUTLINE DIMENSION

#### 8 pin MSOP Package Outline Dimension









SYMBOLS	MIN.	NOM.	MAX.	
Α	-	_	1.10	
A1	0.00	_	0.15	
A2	0.75	0.85	0.95	
D	3.00 BSC			
E	4.90 BSC			
E1	3.00 BSC			
L	0.40 0.60 0.80			
L1	0.95 REF			
θ*		- 8		

UNIT : MM

NOTES:

1.JEDEC OUTLINE: MO-187 AA

2.DIMENSION 'D' DOES NOT INCLUDE MOLD FLASH,
PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS
OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

3.DIMENSION 'E1' DOES NOT INCLUDE INTERLEAD FLASH OR
PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL
NOT EXCEED 0.25 PER SIDE.

4.DIMENSION '0.22' DOES NOT INCLUDE DAMBAR PROTRUSION.
ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 MM
TOTAL IN EXCESS OF THE '0.22' DIMENSION AT MAXIMUM
MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE
LOWER RADIUS OF THE FOOT. MINIMUM SPACE BETWEEN
PROTRUSION AND ADJACENT LEAD IS 0.07 MM.

5.DIMENSIONS 'D' AND 'E1' TO BE DETERMINED AT DATUN
PLANE ...

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